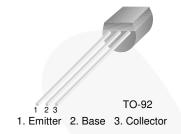


November 2014

KSP2222A NPN General-Purpose Amplifier

Features

- Collector-Emitter Voltage: V_{CEO} = 40 V
- · Available as PN2222A



Ordering Information

| Part Number | Marking | Package | Packing Method |
|-------------|---------|----------|----------------|
| KSP2222ABU | KSP2222 | TO-92 3L | Bulk |
| KSP2222ATA | KSP2222 | TO-92 3L | Ammo |
| KSP2222ATF | KSP2222 | TO-92 3L | Tape and Reel |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|------------------|---------------------------|-------------|------|
| V _{CBO} | Collector-Base Voltage | 75 | V |
| V _{CEO} | Collector-Emitter Voltage | 40 | V |
| V _{EBO} | Emitter-Base Voltage | 6.0 | V |
| I _C | Collector Current | 600 | mA |
| TJ | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 to +150 | °C |

Thermal Characteristics(1)

Values are at $T_A = 25$ °C unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|-----------------|---|-------|-------|
| В | Power Dissipation by R _{0JA} | 625 | mW |
| P_{D} | Derate Above 25°C | 5 | mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction-to-Case | 83.3 | °C/W |
| $R_{\theta JA}$ | Thermal Resistance, Junction-to-Ambient | 200 | °C/W |

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

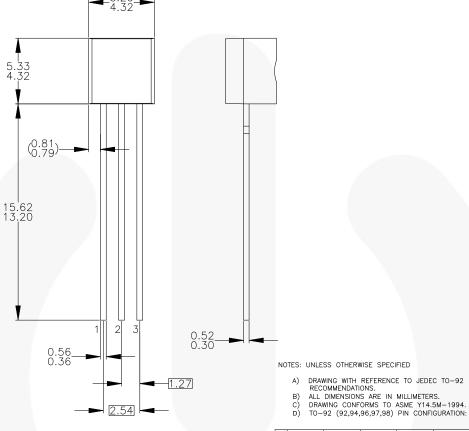
Values are at $T_A = 25$ °C unless otherwise noted.

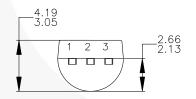
| Symbol | Parameter | Conditions | Min. | Max. | Unit | | |
|-----------------------|---|---|------|------|-------|--|--|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_C = 10 \mu A, I_E = 0$ | 75 | | V | | |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | $I_C = 10 \text{ mA}, I_B = 0$ | 40 | | V | | |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10 \mu A, I_C = 0$ | 6.0 | | V | | |
| I _{CBO} | Collector Cut-Off Current | $V_{CB} = 60 \text{ V}, I_{E} = 0$ | | 0.01 | μΑ | | |
| I _{EBO} | Emitter Cut-Off Current | $V_{EB} = 3.0 \text{ V}, I_{C} = 0$ | | 10 | nA | | |
| | | $V_{CE} = 10 \text{ V}, I_{C} = 0.1 \text{ mA}$ | 35 | | | | |
| | | $V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$ | 50 | | | | |
| h_{FE} | DC Current Gain | $V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$ | 75 | | | | |
| | | $V_{CE} = 10 \text{ V}, I_{C} = 150 \text{ mA}^{(2)}$ | 100 | 300 | | | |
| | | $V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}^{(2)}$ | 40 | | | | |
| M (1) | Callector Emitter Seturation Valtage (2) | I _C = 150 mA, I _B = 15 mA | | 0.3 | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage ⁽²⁾ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 1.0 | - V | | |
| M (1) | Dana Franklau Catawatian Valtana(2) | I _C = 150 mA, I _B = 15 mA | 0.6 | 1.2 | \ | | |
| V _{BE} (sat) | Base-Emitter Saturation Voltage ⁽²⁾ | $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$ | | 2.0 | 2.0 V | | |
| f _T | Current Gain Bandwidth Product | I _C = 20 mA, V _{CE} = 20 V, f = 100 MHz | 300 | | MHz | | |
| C _{ob} | Output Capacitance | V _{CB} = 10 V, I _E = 0, f = 1.0 MHz | | 8 | pF | | |
| t _{ON} | Turn-On Time | V _{CC} = 30 V, I _C = 150 mA, I _{B1} = 15 mA, V _{BE(off)} = 0.5 V | | 35 | ns | | |
| t _{OFF} | Turn-Off Time | $V_{CC} = 30 \text{ V}, I_{C} = 150 \text{ mA},$ $I_{B1} = I_{B2} = 15 \text{ mA}$ | | 285 | ns | | |
| NF | Noise Figure | $I_C = 100 \ \mu A, \ V_{CE} = 10 \ V, \ R_S = 1 \ k\Omega, \ f = 1.0 \ kHz$ | | 4 | dB | | |

Note:

2. Pulse test: Pulse width $\leq 300~\mu s,$ duty cycle $\leq 2\%$

Physical Dimensions



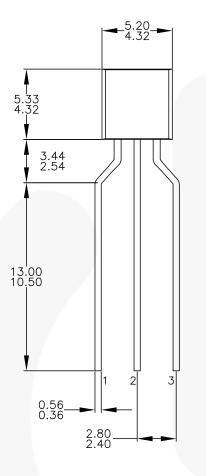


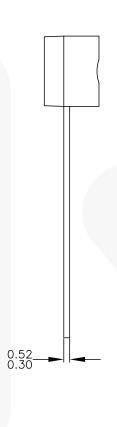
| Z | | 92 | | 94 | | 96 | | 9/ | | | 98 | | | | |
|-----|----|-----|---|----|---|----|---|----|---|---|----|---|---|---|---|
| ā | Р | F | М | Ρ | F | М | В | F | М | Р | F | М | Ρ | F | М |
| 1 | Ε | S | S | Ε | S | S | В | D | G | С | G | D | О | G | D |
| 2 | В | D | G | C | G | D | Ε | S | S | В | D | G | Ε | S | S |
| 3 | С | G | D | В | D | G | С | G | D | Ε | S | S | В | D | G |
| 1.6 | CE | ın. | | | | | | | | | | | | | |

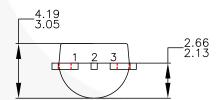
- P BIPOLAR F JFET M DMOS E - EMITTER B - BASE C - COLLECTOR
- E) FOR PACKAGE 92, 94, 96, 97 AND 98:
 PIN CONFIGURATION DRAIN "D" AND SOURCE "S"
 ARE INTERCHANGEAGLE AT JFET "F" OPTION.
 F) DRAWING FILENAME: MKT-ZAOSDREVS.

Figure 1. 3-Lead, TO-92, JEDEC TO-92 Compliant Straight Lead Configuration, Bulk Type

Physical Dimensions (Continued)







NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC. ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5M-2009. DRAWING FILENAME: MKT-ZAO3FREV3. FAIRCHILD SEMICONDUCTOR.

Figure 2. 3-Lead, TO-92, Molded, 0.2 In Line Spacing Lead Form, Ammo, Tape and Reel Type





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